



FORM PTO-1489 A and B (Modified)

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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APPLICANT: Kevin E. Brehmer

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EXAMINER: Justin P. Misleh

U.S. PATENT DOCUMENTS

Examiner's Initials	Cite No.	U.S. Patent Document		Name of Patentee or Applicant of Cited Document	Date of Publication or of issue of Cited Document MM-DD-YYYY
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		Office/ Country	Number	Kind Code			
JM		GB	2160060	A	Eouzan, et al.	12-1985	

OTHER ART — NON PATENT LITERATURE DOCUMENTS

Examiner's Initials	Cite No	Include name of the author (in CAPITAL LETTERS) title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, relevant page(s), volume-issue number(s), publisher, city and/or country where published.	Translation (Y/N)
JM		CHAMBERLAIN, S.G., "Photosensitivity and Scanning of Silicon Image Detector Arrays," IEEE Journal of Solid-State Circuits, December 1969, pgs. 333-342	<input checked="" type="checkbox"/>
JM		OHBA, SHINYA, ET AL, "MOS Area Sensor: Part II-Low Noise MOS Area Sensor with Antiblooming Photodiodes," IEEE Transactions on Electron Devices, Vol. Ed 27, No. 8, August 1980, pgs. 1682-1687	<input checked="" type="checkbox"/>

EXAMINER	/Justin Misleh/	DATE CONSIDERED	08/22/2006
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is a published U.S. Patent or U.S. Patent application and the present application was filed after June 30, 2003.